Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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SiC Microsemi

Microsemi POWER PRODUCTS GROUP

APT30SCD120B
APT30SCD120S

1200V 30A

Zero Recovery Silicon Carbide Schottky Diode

PRODUCT APPLICATIONS

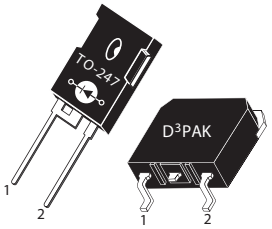
- **Anti-Parallel Diode**
  - **-Switchmode Power Supply**
  - **-Inverters**
- **Power Factor Correction (PFC)**

PRODUCT FEATURES

- **Zero Recovery Times (t_{rr})**
- **Popular TO-247 Package or surface mount D³PAK package**
- **Low Forward Voltage**
- **Low Leakage Current**

PRODUCT BENEFITS

- **Higher Reliability Systems**
- **Minimizes or eliminates snubber**



1 - Cathode
2 - Anode
Back of Case - Cathode

MAXIMUM RATINGS

T_C = 25°C unless otherwise specified.

Symbol	Characteristic / Test Conditions		Ratings	Unit
V_R	Maximum D.C. Reverse Voltage		1200	Volts
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			
V_{RWM}	Maximum Working Peak Reverse Voltage			
I_F	Maximum D.C. Forward current	T_C = 25°C	99	Amps
		T_C = 135°C	29	
I_{FRM}	Repetitive Peak Forward Suge Current (T_J = 45°C, t_p = 10ms, Half Sine Wave)		150	
I_{FSM}	Non-Repetitive Forward Surge Current (T_J = 25°C, t_p = 10ms, Half Sine)		330	
P_{tot}	Power Dissipation	T_C = 25°C	291	W
		T_C = 125°C	93	
T_J, T_{STG}	Operating and Storage Junction Temperature Range		-55 to 150	°C
T_L	Lead Temperature for 10 Seconds		300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		Min	Typ	Max	Unit
V_F	Forward Voltage	I_F = 30A T_J = 25°C		1.5	1.8	Volts
		I_F = 30A, T_J = 150°C		2.1		
I_{RM}	Maximum Reverse Leakage Current	V_R = 1200V T_J = 25°C			600	µA
		V_R = 1200V, T_J = 150°C			3000	
Q_c	Total Capactive Charge V_R = 800V, I_F = 30A, di/dt = -100A/µs, T_J = 25°C			200		nC
C_T	Junction Capacitance V_R = 0V, T_J = 25°C, f = 1MHz			2100		pF
	Junction Capacitance V_R = 200V, T_J = 25°C, f = 1MHz			228		
	Junction Capacitance V_R = 400V, T_J = 25°C, f = 1MHz			167		

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	Min	Typ	Max	Unit
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			0.43	°C/W
W_T	Package Weight		0.22		oz
			5.9		g
Torque	Maximum Mounting Torque			10	lb·in
				1.1	N·m

Microsemi reserves the right to change, without notice, the specifications and information contained herein.

TYPICAL PERFORMANCE CURVES

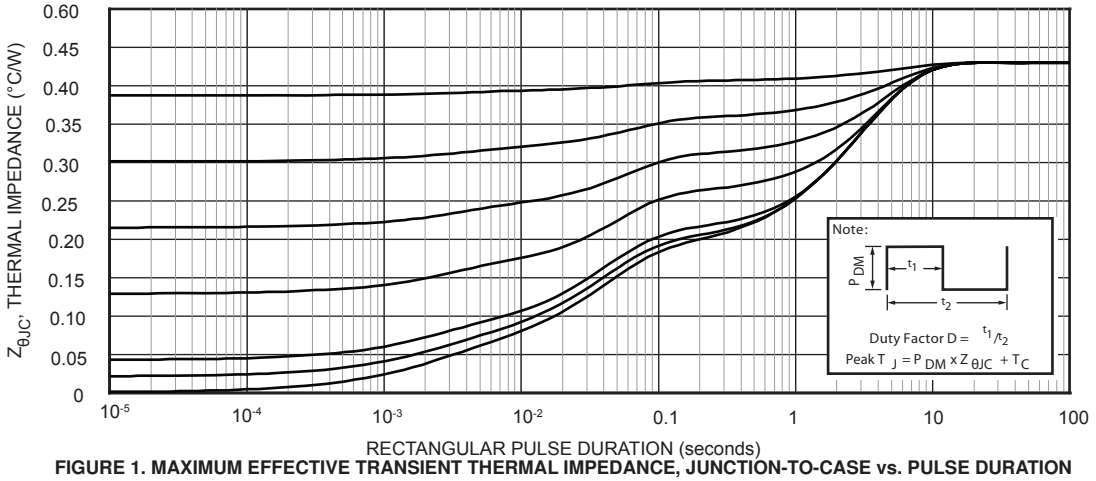


FIGURE 1. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

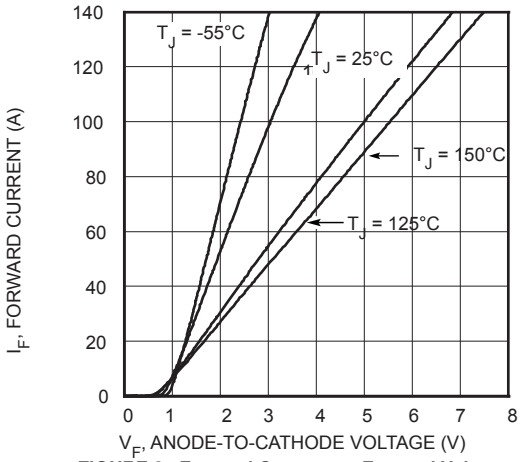


FIGURE 2, Forward Current vs. Forward Voltage

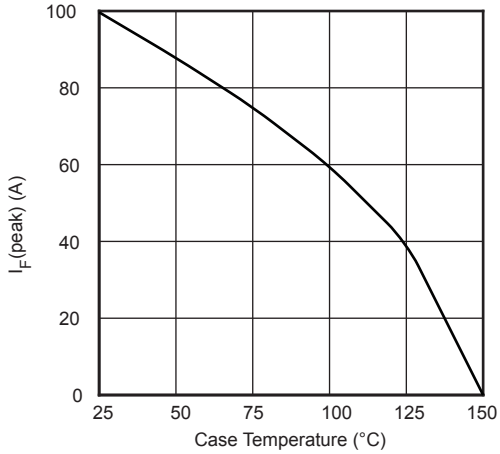


FIGURE 3, Maximum Forward Current vs. Case Temperature

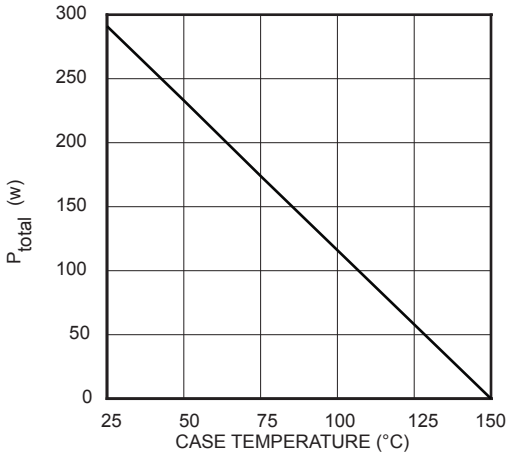


Figure 4. Maximum Power Dissipation *vs.* Case Temperature

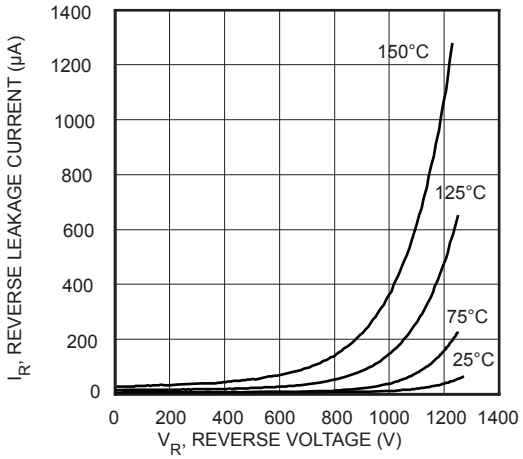


Figure 5. Reverse Leakage Currents *vs.* Reverse Voltage

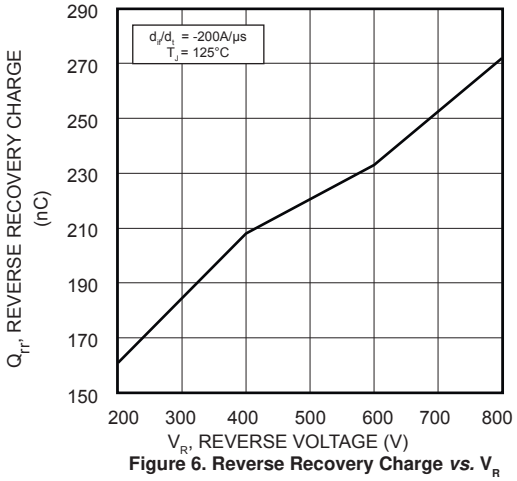


Figure 6. Reverse Recovery Charge *vs.* V_R

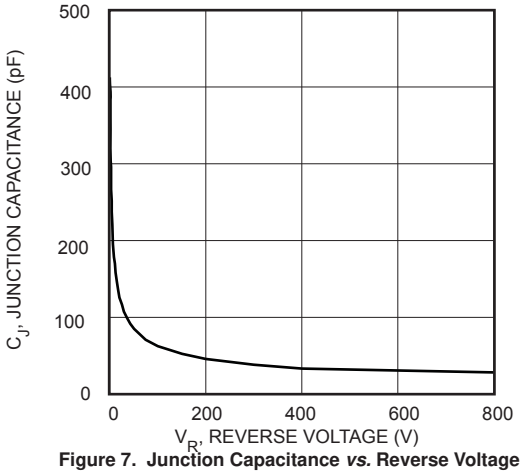
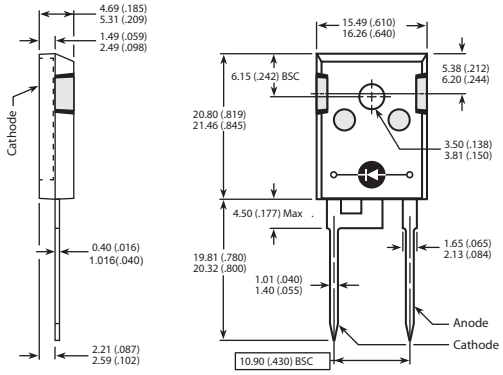


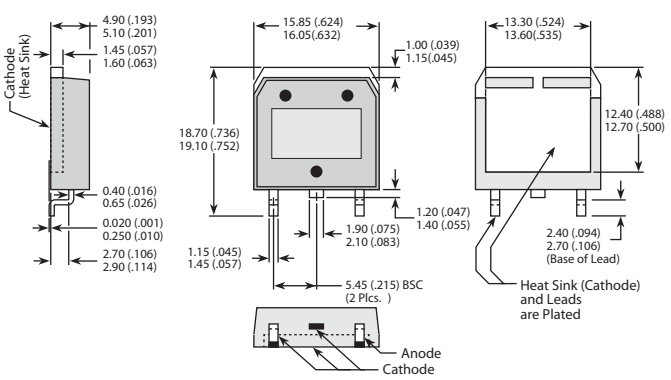
Figure 7. Junction Capacitance *vs.* Reverse Voltage

TO-247 Package Outline



Dimensions in Millimeters and (Inches)

D³PAK Package Outline



Dimensions in Millimeters and (Inches)

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